Characterization of ZnSe scintillating bolometers for Double Beta Decay

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1. Introduction

Neutrinoless Double Beta Decay ($\beta\beta(0\nu)$) is, at present, a unique method to investigate basic neutrino properties. The observation of this transition would give insight on the mass pattern of the three neutrino eigenstates and would assess the Majorana character of neutrinos [1]. The purpose of new generation $\beta\beta(0\nu)$ experiments [2–6] is to reach a sensitivity on $(m_{\nu})^2$ of the order of 50 meV, approaching – but probably not completely covering – the so called inverse hierarchy region. The realization of an experiment with a $^{82}$Se high Q-value and thanks to the possibility of alpha background rejection on the basis of the scintillation signal. In this paper we report the characteristics and the anomalies observed in an extensive study of these devices. Among them, an unexpected high emission from alpha particles, accompanied with an unusual pattern of the light vs. heat scatter plot. The perspectives for the application of this kind of detectors to search for the Neutrinoless Double Beta Decay of $^{82}$Se are presented.

2. Scintillating bolometers

Cryogenic particle detectors (also named bolometers) have been proposed since many years for the study of rare events such as $\beta\beta(0\nu)$ and Dark Matter [7]. The excellent detector performance and Physics results obtained by the CUORICINO experiment [8] prove how this technique is competitive in the case of $\beta\beta(0\nu)$ searches.

Unlike other solid state devices, bolometers are not based on ionization but on phonon detection. A bolometer is made of three elements: an absorber where the energy of the particles is deposited and converted into phonons, a phonon sensor that transduces the phonon signal into an electrical pulse and a thermal link to a low temperature (below 100 mK) heat sink that maintains the detector at the optimal temperature.

The working principle of these devices can be summarized as follow. By interacting in the absorber, a particle produces ionization and excitation, which starts triggering a series of processes that lead to the conversion of almost all the deposited energy into phonons (i.e. lattice elementary excitations). Along this path it is possible that a fraction of the energy is trapped in long-living excited states or is lost through the emission of photons that escape the absorber. However, a proper choice of the absorber (usually a single dielectric crystal, with a high Debye temperature and without scintillation properties) allows to reduce to a minimum the importance of these channels and therefore ensures a high efficiency in the conversion of the deposited energy into phonons. The phonon signal is detected through a sensor that modifies its electrical properties when collided with a phonon flux. The dimensions and characteristics of the absorber and of the phonon sensor define the specific performance of the bolometer as far as energy resolution and time-response is concerned.

In the bolometers described in this work the sensor is a semiconductor thermistor glued on the crystal, while the absorber is a large size dielectric crystal (whose heat capacity is expected to dominate over the thermistor one). In this configuration the detector response is extremely slow: the typical rise time is of the order of few ms. Also CUORICINO detectors are calorimeters of this kind. They are crystals of $\text{TeO}_2$, with a mass of 790 g. Their energy resolution at the $\beta\beta(0\nu)$ transition is 7 keV FWHM, quite similar to the performance of a Ge diode. However, when compared with the
more competitive devices used today for $\beta\beta(0\nu)$ decay investigations, it is evident that the main disadvantages of bolometers is the lack of an active background rejection (e.g. particle identification as used in NEMO [9] or single-site vs. multi-site events distinction as in GERDA and Majorana [2,4]). The use of scintillating crystals, as absorbers, can overcome this limitation [10–13], providing a powerful tool to improve the experimental $\beta\beta(0\nu)$ sensitivities.

The detector is in this case obtained by coupling a scintillating crystal – operated as bolometer – to a light detector (Fig. 1). When a particle traverses the scintillating crystal a (large) fraction of the deposited energy is converted into heat (following the chain described above), while a (small) fraction of it is spent to produce scintillation light (i.e. photons irradiated outside the crystal). For each interaction, two signals are recorded: a thermal signal produced in the scintillating bolometer and a photon signal read-out by the light detector. The ratio between the two (heat vs. light) depends on the particle Light Yield (LY). Betas and gammas have the same LY, which is typically different from the LY of alphas or from that of neutrons. Consequently, the contemporary read out of the heat and light signals allows particle discrimination.

In particular, if the scintillating crystal is made of a $\beta\beta$ candidate, the $\beta\beta(0\nu)$ signal (i.e. the energy deposition produced by the two electrons emitted in the decay) can be distinguished from an alpha signal. This makes feasible the rejection of alpha induced background, opening a new window in the future of $\beta\beta(0\nu)$ with bolometers [13]. It is in fact true that, in the recently concluded $\beta\beta$ bolometric experiment CUORICINO, the major source of background is identified in alpha particles due to surface contaminations [14–16]. This same source could be the main factor limiting the sensitivity of the – presently under construction – CUORE experiment [15].

![Fig. 1. Left panel: illustration of the operating principle of scintillating bolometers. The release of energy inside a scintillating crystal follows two channels: light production and thermal excitation. The heat is read out by a temperature sensor (NTD) glued on the primary crystal while the light is read by a second crystal (the light detector) where it is completely converted into heat. Right panel: the ZnSe crystal since many years[25]. Its X-ray induced luminescence has been recently measured from room temperature down to 10 K, resulting in a dominant emission in the red region (610 and 645 nm) [23]. The Light Yield of this crystal (measured on small pieces cut from the same ingot from which the Small ZnSe crystal was obtained) was observed to increase at low temperature, with an emission characterized by more than one decay constant [26].

In all the runs discussed here, the crystals were mounted in a Copper frame and tightly kept in position by PTFE tips. They were surrounded (without being in thermal contact) by a reflecting

### 3. $^{82}\text{Se} \beta\beta(0\nu)$ decay

$^{82}\text{Se}$ is a $\beta\beta$ emitter with an isotopic abundance of 9.2% and a Q-value of (2995.5 ± 2.7) keV [17]. It has always been considered a good candidate for $\beta\beta(0\nu)$ studies because of its high transition energy and the favorable nuclear factor of merit. Indeed, the more recent evaluations of the Se nuclear matrix element (NME), yield for this isotope a half-life in the range 1–8·10$^{26}$ years for an [$(m_{\nu})$] value of 50 meV [18–21] (in the same condition the predicted half-life for $^{76}\text{Ge}$ is about 4 times larger).

In recent years the NEMO collaboration measured its half life for Two Neutrino Double Beta Decay ($\beta\beta(2\nu)$) to be $9.6 \pm 0.3 ($stat$) \pm 1.0 ($syst$) \cdot 10^{19}$ years and set an upper bound on the $\beta\beta(0\nu)$ half-life of 1.0 · 10$^{23}$ years at 90% CL [22].

In view of the realization of a high sensitivity $\beta\beta(0\nu)$ experiment, the low isotopic abundance of $^{82}\text{Se}$ is a potential problem. Indeed, the experimental sensitivity depends on the number of $\beta\beta$ emitters. With natural Se a huge mass of material would be needed to have a reasonable number of $\beta\beta$ emitters. However, this problem can be solved by isotopic enrichment, as done – for this same isotope – by the NEMO collaboration [9].

On the other hand, the high Q-value is an important factor of merit since places the $\beta\beta(0\nu)$ signal in an energy region scarcely populated by the emissions due to natural radioactivity. This means that, in a calorimetric experiment, where the sum energy of the two electrons is recorded, a reduced number of sources contributes to the background and limits the experimental sensitivity [13]. The measured $\beta\beta(2\nu)$ half-life allows to evaluate the irreducible background due to this decay channel, that – for a calorimetric experiment with high resolution – results completely negligible (the background issue will be discussed in detail in Section 6).

### 4. Experimental details

The results here discussed are a synthesis of an R&D work performed over more than 2 years during which we have extensively studied the performances of ZnSe detectors in different conditions.

For our studies we have used three different ZnSe crystals whose characteristics are reported in Table 1. The crystals have been produced by Alkor Technologies (Saint-Petersbourg, Russia) and are undoped (usually ZnSe is doped with Te), their color variation is not fully understood, could be ascribed to a different stoichiometry [23].

ZnSe is a semiconductor with a Debye temperature of about 270 K [24] (not much different from TeO$_2$), known as a luminescent crystal since many years [25]. Its X-ray induced luminescence has been recently measured from room temperature down to 10 K, resulting in a prominent emission in the red region (610 and 645 nm) and a smaller component in the infrared region (970 nm) [23]. The Light Yield of this crystal (measured on small pieces cut from the same ingot from which the Small ZnSe crystal was obtained) was observed to increase at low temperature, with an emission characterized by more than one decay constant [26].

In all the runs discussed here, the crystals were mounted in a Copper frame and tightly kept in position by PTFE tips. They were surrounded (without being in thermal contact) by a reflecting

### Table 1

ZnSe crystal characteristics. In the last column the surface quality is indicated for the lateral surface and the two basis of the cylinder, respectively. O stands for optical and R for rough.

<table>
<thead>
<tr>
<th>Crystal name</th>
<th>Crystal color</th>
<th>Mass [g]</th>
<th>Diameter [mm]</th>
<th>Height [mm]</th>
<th>Surface quality</th>
</tr>
</thead>
<tbody>
<tr>
<td>Small</td>
<td>Yellow</td>
<td>37.5</td>
<td>20</td>
<td>21</td>
<td>O O O</td>
</tr>
<tr>
<td>Large</td>
<td>Red</td>
<td>120</td>
<td>41</td>
<td>17</td>
<td>O R R</td>
</tr>
<tr>
<td>Huge</td>
<td>Orange</td>
<td>337</td>
<td>40</td>
<td>50</td>
<td>O O O</td>
</tr>
</tbody>
</table>
sheet (3 M VM2002), but for the side which is faced to the light detector (LD), as shown Fig. 1. The tests have been performed operating the ZnSe scintillating bolometers at about 15 mK, in a low temperature refrigerator installed underground in Hall C of Laboratori Nazionali del Gran Sasso (LNGS), L’Aquila, Italy. A group of more than 10 cryogenic runs, with a duration ranging from 1 month to few months, have been realized in order to come to the results described in this paper. In all these runs the bolometers worked properly, proving that this crystal bears thermal cycles without a deterioration of its performances, whereas it exhibits an abnormal cooling slowness.

Details of the set-up and the read-out are discussed in the next two sub-sections.

4.1. ZnSe bolometers and the heat signal

Each ZnSe bolometer was equipped with a Neutron Transmutation Doped Ge thermistor (NTD) [27], glued on the crystal surface and used as a thermometer to measure the heat signal produced by particles traversing the ZnSe. A silicon resistance, glued on the crystals, was used to produce a calibrated heat pulse in order to monitor the thermal gain of the bolometer. This is indeed subject to variation upon temperature drifts of the cryostat that can spoil the energy resolution. In most cases this temperature drift can be re-corrected off-line on the basis of the measured thermal gain variation [28,29].

The NTD thermistor transduces the heat pulse into a voltage signal which is amplified and fed into a 16 bit ADC. The entire waveform (raw pulse) is sampled, digitized and acquired. At the ADC input, a low pass Bessel filter is used as antialiasing to avoid spurious contributions in the sampled signal [30].

The amplitude and the shape of each voltage pulse $V(t)$ are then determined by the off-line analysis that makes use of the Optimal Filter technique [30,31]. $H(t)$ is the transfer function of the Optimal Filter that allows to achieve – in the more general conditions – the best possible signal-to-noise ratio in amplitude estimation. In the frequency domain the transfer function of the Optimal Filter can be written as:

$$H(\omega) = \eta \frac{R(\omega)}{|N(\omega)|^2}$$

where $\eta$ is a normalization factor, $R(\omega)$ is the response function of the detector\(^{1}\) and $N(\omega)$ its noise power spectrum.

The signal amplitude is computed as the maximum of the optimally filtered pulse $A(t) = H(t) \otimes V(t)$ (where $\otimes$ stands for the convolution operator).

The signal shape is evaluated using four different parameters: $t_{\text{rise}}$ and $t_{\text{decay}}$, TVL and TVR.

$t_{\text{rise}}$ (the rise time) and $t_{\text{decay}}$ (the decay time) are determined on the raw pulse as $(t_{300} - t_{100})$ and $(t_{300} - t_{500})$, respectively. For these detectors they are of the order of 5–10 ms and 20–30 ms. The rise time is mainly dominated by the time constant of the absorber-glue-sensor interface, while the decay time is determined by the crystal heat capacity and by its thermal conductance towards the heat sink.

TVR (Test Value Right) and TVL (Test Value Left) are computed on the optimally filtered pulse $A(t)$, they are the least square differences with respect to the filtered response function $A_{0}(t) = H(t) \otimes R(t)$. In more detail, the filtered response function $A_{0}(t)$ is synchronized with the filtered signal $A(t)$, making their maxima to coincide, then the least square differences of the two functions are evaluated on the right (TVR) and left (TVL) side of the maximum. These two parameters do not have a direct physical meaning, however they are very much sensitive (even in noisy conditions) to any difference between the shape of the analyzed pulse and the response function. Consequently, they are used either to reject fake triggered signals (e.g. spikes) or to identify variations in the pulse shape with respect to the response function (and this will be our case, as in Section 5.3).

In each run, the ZnSe bolometers were calibrated with a $^{232}$Th source placed between the cryostat and its external lead shield. Gamma lines between 238 keV and 2615 keV were used for amplitude ($V_{\text{heat}}$) vs. energy ($E$) linearization of the heat signal. The response of the bolometer is indeed slightly non linear, mainly because of the exponential dependence of the NTD thermistor resistance from temperature. In Fig. 2 we report the ratio $V_{\text{heat}}/E$ vs. $E$ (where $E$ is the full energy of the corresponding gamma peak) observed for one of our detectors. The points with $E < 3$ MeV correspond to gamma peaks identified in the heat signal spectrum, the others correspond to alpha lines (these are due to a $^{224}$Ra source facing the detector, see Section 5 and Fig. 4 for more details). The non linearity measured on gamma lines is here of about 3% on a 3 MeV energy range. Non linearities of the same order of magnitude are observed for all the other detectors. As it is usually done for other bolometers [16,32], the non-linearity is corrected by introducing the calibrated amplitude of the heat pulse ($Heat$) – obtained from $V_{\text{heat}}$ – using the following relationship:

$$\log(Heat) = A + B \log(V_{\text{heat}}) + C \log(V_{\text{heat}})^2$$

where the three coefficients $A$, $B$ and $C$ are determined fitting the $\left(\frac{V_{\text{heat}}}{E}\right)$ points of the calibration gamma lines. It is worth to note that in this way we attribute to the heat signal the nominal energy $E$ of the detected gamma line, i.e. the calibration returns $Heat = E$ for gamma particles. Here $E$ is the total energy lost within the crystal, while only a fraction of it is converted into heat. The other fraction is spent in scintillation light or in possible blind channels such as long living metastable states. The result obtained after the calibration is shown in Fig. 2: the colored circles are the ratio $Heat/E$ for each gamma and alpha line. The calibration returns, as expected, $Heat/E = 1$ for all the gamma lines. While for alpha lines $Heat/E > 1$ (all the points with $E > 3$ MeV in Fig. 2). This means that alpha lines appear in the Heat spectrum with a displacement of about

\[^{1}\text{The response function of the bolometer, i.e. the shape of a pulse in absence of noise, is computed with a proper average of a large number of raw pulses.}\]
of a 600 Å layer of SiO₂ in order to increase the light absorption. We facing the scintillating crystal are in diameter and 1 mm in thickness. The surface of the Ge wafers temperature increase upon photon absorption). They are 36 mm in the case of the ZnSe Small crystal we have not been able to evaluate the energy resolution because no gamma peak is visible in the calibration or background spectra. This is explained by the small dimensions of the crystal and its low Z. Since we only used it at the beginning of our studies on ZnSe, we did not have the occasion for a long calibration measurement.

4.2. Light detectors and the photon signal

The scintillation light emitted by the ZnSe crystals is detected with small bolometers [33]. These are made by high purity Ge wafers with a large area (to optimize photon collection) but a small mass (to reduce the heat capacity and therefore to have a sizable temperature increase upon photon absorption). They are 36 mm in diameter and 1 mm in thickness. The surface of the Ge wafers facing the scintillating crystal are darkened through the deposition of a 600 Å layer of SiO₂ in order to increase the light absorption. We have used also a very large area Ge wafer (66 mm in diameter) able to cover contemporary the Small and Large ZnSe crystals in order to provide a direct comparison of their Light Yields.

The Ge wafers are provided, as the ZnSe bolometer, with an NTD thermistor for the temperature read-out and with a Si resistor for gain monitoring. Electronics and DAQ are identical to that of ZnSe scintillators. Rise and decay times of the signal are of about 2 and 15 ms, respectively.

The Ge wafer are too small to be able to detect the energetic gamma lines of the 232Th source used for ZnSe calibration. Therefore a weak 55Fe source was faced to the Ge wafers, on the side opposite to the crystal scintillator, for calibration purposes. The 5.9 keV Kα, X-ray line of 55Fe was used to measure the energy resolution of the detector and its amplitude to energy conversion. Obviously, with only one calibration peak, we are not able to correct the Light amplitude for the non linearity of the LD response. However, the expected non linearity is similar to the one recorded for the scintillating bolometer (since the NTD sensor is similar) while the energy range is smaller by more than one order of magnitude. The effect should be therefore negligible.

The 55Fe calibration provides a method to measure and compare the LY’s of different crystals. This cannot be used for an absolute evaluation of the amount of scintillation light emitted by the crystal since the Light amplitude is not corrected for the photon collection efficiency that is certainly below 1. Finally the energy resolution of the LD is measured as the FWHM of the 5.9 keV line. Depending on the detector used and on the working conditions, the resolutions range from 200 eV to 600 eV FWHM. These resolutions are negligible if compared with the width of gamma and alpha lines in the Light spectrum.

5. Results

We discuss in this section the results obtained in several runs performed in the last few years, with the three above mentioned crystals. Our measurements aimed mainly at the study of the alpha vs. beta/gamma discrimination properties of ZnSe, at the evaluation of the LY and of the Quenching Factor (QF), and at the study of the variation of these properties upon variation of the crystal color and surface quality. In order to be able to compare the detector response to alpha and beta/gamma particles, in most of the runs, the crystals were faced to low intensity alpha sources (while gammas were generated with the external 232Th source used for calibration). Two different radio-isotopes have been used so far.

Source A was obtained by implantation of 224Ra in an Al reflecting stripe. The implantation was accomplished by exposing the stripe to a thin 228Ra source. The 228Th isotopes contained in the source alpha decay to 224Ra. The recoil energy of 224Ra is sometimes enough to eject the nucleus from the source and implant it in the Al stripe. The extremely short range of nuclear recoils in solid materials allows to obtain a very shallow depth source (this can be appreciated in Fig. 4 from the symmetry of the peaks). Besides several alpha lines of different relative intensity, this source also produce beta particles with a maximum energy of 5 MeV due to the beta decay of 208Tl.

Source B was obtained contaminating an Al stripe with a 238U liquid solution and later covering the stripe with an illuminated Mylar film (6 μm thick). Thus the source has a continuous spectrum extending from about 3 MeV to 0.

The usual way to visualize alpha vs. beta discrimination is to draw the Light vs. Heat scatter plot. Here each event is identified with the number of counts/hour at the energy of the 5.9 keV line. In the inset the highlight of the 2615 keV line. The gain in resolution on all the lines is evident.
by a point whose abscissa is equal to the Heat signal amplitude (recorded by the scintillating bolometer), and ordinate equal to the Light signal amplitude (simultaneously recorded by the LD). In the scatter plot beta/gamma, alphas and neutrons give rise to separate bands, in virtue of their characteristic Light to Heat ratio. As already anticipated, this feature is the result of the different LY’s characterizing these particles.

The Light vs. Heat scatter plot of the ZnSe Huge crystal, exposed to the calibration gamma source ($^{222}$Th) and to the alpha source B, is shown in Fig. 5. This scatter plot (as well as all the others we obtained with ZnSe crystals) is completely different from any other we ever measured with different scintillating crystals (we tested several scintillating bolometers like CdWO$_4$, ZnMoO$_4$ and CaMoO$_4$). Three anomalies are indeed here evident:

1. monochromatic gamma peaks lie on positive slope lines (right panel of Fig. 5), whereas a negative slope is expected;
2. the alpha band lies above the beta/gamma band, suggesting an alpha QF larger than one (left panel of Fig. 5);
3. alphas are always accompanied with a tail that draws negative slope lines (Fig. 8).

The anomalies resulted reproducible for the three crystals, despite the different crystal color and size and despite the different experimental conditions. In the following three sections we document these unexpected features and try to give a possible interpretation of them.

5.1. Correlation between Heat and Light and energy resolution on gammas

In a standard scintillator, monochromatic events (i.e. those corresponding to the complete absorption of a monochromatic particle in the scintillating crystal) appear as sections of lines with negative slope, showing an anticorrelation between Heat and Light [32,34]. The observed spread along a negative slope line can be accounted for assuming the existence of fluctuations in the Heat and Light signal amplitudes. Since the energy has to be conserved, the amplitude of the fluctuations ($\Delta$Light and $\Delta$Heat) must compensate each other: $\Delta$Heat = $\Delta$Light. In other words the fluctuations are anti-correlated and produce the observed pattern. Finally, they are visible because their amplitude is much larger than the intrinsic resolution of the detectors. This is what happens for example for CdWO$_4$ crystals. In this case a rotation of the axis can be used to improve the energy resolution of the detector [32,34].

In ZnSe crystals the slope of gamma lines is clearly positive (see right panel of Fig. 5): for a monochromatic event (as it is the photopeak of a gamma line) the minimum heat release corresponds to the maximum of light emission, and vice versa. It seems that fluctuations in the energy conversion into heat and light are correlated, and that there is a lacking energy which is feeding some invisible channel.

The data presently in our hands are not enough to proceed further in the modeling of this unusual behaviour of ZnSe scintillator, we simply observe that – also in this configuration – a rotation of the axis [32] can be used to improve the energy resolution of the detector.

Fig. 3 shows (filled histogram) the spectrum obtained projecting the gamma events of Fig. 5 on the Heat axis. The black line histogram is obtained by projecting events on a rotated axis (Heat$_o$) defined as:

$$\text{Heat}_o = \text{Heat} \cos(\theta) - \text{Light} \sin(\theta)$$

where the rotation angle $\theta$ is chosen in order to reach the minimum FWHM for the 2615 keV. The improvement obtained on the resolution is of about a factor 3 on the 2615 keV line of $^{208}$Tl (the FWHM is reduced from 28 ± 1 keV to 9.5 ± 0.4 keV). On the other peaks the improvement is smaller: at 911 keV from 7.8 ± 0.6 keV to 5.9 ± 0.3 keV, at 583 keV from 7.5 ± 0.5 keV to 5.4 ± 0.3 keV. Provided that it is proved that also $\beta$/$\gamma$ events would give rise to a monochromatic line with the same slope, this technique could be used to improve the resolution of the detector.

5.2. Light Yield and anomalous light emission from the alphas

The Light Yield of a crystal is conventionally defined as the fraction of the total energy deposited in the scintillator which is converted into light. As discussed previously, we do not have an absolute calibration of the Light signal, therefore we can provide only a relative evaluation of the Light Yield defined as:

$$\text{LY}_\gamma = \frac{\text{Light}}{\text{Energy}_\gamma}$$

A similar definition holds for alphas. In our case, we chose to evaluate the $\text{LY}_\gamma$ on the 2615 keV line of $^{208}$Tl (i.e. $\text{Energy}_\gamma = 2.615$ keV). The results for our 3 crystals are reported in Table 2.

The QF$_\gamma$ is usually defined as the ratio between the amplitudes of the light pulses corresponding to alpha and beta/gamma particles of the same energies. It is however difficult to have alpha and beta/gamma sources with monochromatic lines of the same energies therefore we have evaluated the QF$_\gamma$ as:

$$QF_{\gamma} = \frac{\text{Light}_\gamma}{\text{Energy}_\gamma} \cdot \frac{\text{Energy}_\gamma}{\text{Light}}$$

where we always compare the 5.7 MeV alpha line of the implanted source with the 2615 keV gamma line of the $^{232}$Th source.
The QF obtained for the Small, Large and Huge crystals, for an identical position of the alpha source (i.e. facing the crystal basis opposite to the LD) are reported in Table 2. QF$_a$ values are definitely larger than 1, and this unusual feature is accompanied by other peculiar behaviours that we extensively investigated in several dedicated runs. The experimental results and the conclusions that can be drawn are discussed in the next subsections.

5.2.1. The anomalous alpha QF

To our knowledge, no other scintillator with a QF$_a$ definitely higher than 1 have ever been reported in literature. This feature cannot be easily accommodated within the theoretical framework used to describe the scintillation properties of materials. Indeed, heavy particles usually have QF$_a$ lower than one and this is explained on the basis of a saturation effect due to the high ionization density that characterizes the interaction of heavy particle in matter \cite{35}. The few results on ZnSe QF$_a$ reported in literature (\cite{37,38}) are hard to be compared with ours since they refer to very thin doped samples, measured at high temperature; while our work was done with large undoped crystals operated below 50 mK.

During our investigations, we have considered the possibility that a QF$_a$ larger than 1 could be due to the experimental configuration, in some way privileging the collection of photons emitted by the point-like external alpha source with respect to the light produced in crystal bulk by gamma rays. We considered possible effects due to:

- Light collection, comparing two crystals – the ZnSe Huge and a CdWO$_4$ of the same size – in an identical configuration. The result was a normal behavior in the CdWO$_4$ case (with a LY$_1$ of 17 keV/MeV \cite{32}) and an anomalous one in the ZnSe case.

- Scintillation light self-absorption, that could penalize gamma (bulk) emission with respect to alpha (surface) emission. All the QF's reported in Table 2 have been measured with an alpha source placed on the side opposite to the LD, in such a way that only the light traversing the crystal could be detected. The QF$_a$ are well above 1.

- Transparency of the LD's to the scintillation photons. Although Ge wafers are completely opaque to the red light that dominates ZnSe luminescence at room temperature \cite{23}, a variation with temperature of the emission band could be possible. However, we did not observe relevant modification in the measured LY's and QF's when using – as LD – a sapphire bolometer covered with a lead substrate (completely opaque from IR to UV).

All our measurements, and consequently the above reported considerations, have been based on external alpha sources since we have never observed – in our crystals – an internal alpha line. We investigated the possibility that bulk alphas do not scintillate, in this case we should see heat signals in anticoincidence with light ones. These dark counts are present in our spectra, but with the same percentage in the alpha and gamma region. They can in fact be ascribed to a light–heat coincidence lost due to trigger inefficiency on one of the two channels.

Finally, the value of the QF$_a$ may depend on the parameter that is used to measure the energy content of the recorded pulse. In our case this is the pulse height. As it will be discussed in Section 5.3, we observe a difference between the shape of alpha and beta/gamma light pulses (see Fig. 6). If the pulse area is used as an energy estimator, the QF$_a$ results lower than what reported in Table 2 (by about a factor 1.5), but still much higher than 1.

5.2.2. QF dependence on source position

The QF$_a$ appears to have a dependence on source position, as can be appreciated from Fig. 7. As a consequence – in the case of a source distributed uniformly around the crystal (and not a point-like source like those we are using) – we should observe an alpha band spanning a much larger angle than what is observed in our scatter plots (roughly the region between the dotted lines in Fig. 7). Based on this observation, it is very likely that the alpha events clearly visible in Fig. 5 and grouped at Heat $\sim$6.2 MeV and Light $\sim$80 keV can be ascribed to a uniformly distributed $^{210}$Po alpha source surrounding the crystal. Indeed, the events draw a positive slope line (similar to the ones observed for monochromatic gamma lines, see Section 5.1) spanning a rather wide range of QF$_a$ (as we could expect for a not localized source).\footnote{The line has an evident tail toward low Light – high Heat signals, an indication (as will be discussed in Section 5.2.3) that it is due to a surface contamination. Based on a test done with two LD (where therefore the collection efficiency was definitely improved) we exclude that the QF$_a$ position dependence could be due to a different photon collection efficiency, while it could be due to a position dependence of the LY's (a similar effect is discussed in \cite{39}) or to the self-absorption of the emitted light.} We observe a different photon collection efficiency, while it could be due to a position dependence of the LY$_1$ (a similar effect is discussed in \cite{39}) or to the self-absorption of the emitted light.

5.2.3. Low Light tails of the alphas in the scatter plot

As anticipated in the previous section, the separation of the alpha band from the beta/gamma one is not complete. This is evident...
looking at monochromatic alpha lines, like those produced by source A. For each monochromatic line, we observe a spot plus a long tail of events – with lower light and larger heat – that draws a negative slope line on the scatter plot (see Fig. 8). Obviously the same effect produces – in the case of source B – a continuum without evident structures below the alpha band. This feature is potentially dangerous since the purpose of our search is the development of a detector able to identify and reject exactly surface alphas. Indeed, this is the most pernicious background source limiting the sensitivity of the CUORICINO experiment. We have observed that this problem appears to be connected to the quality of crystal surface (or to the presence – on the surfaces – of residuals of the abrasive, non-scintillating, powder used for polishing). Indeed the fraction of events populating the tail toward low light emission is different (for the same crystal) if the alpha source hits an optical face of the detector or a rough face. Fig. 8 illustrates the test we have done and its results. The problem persists, although in reduced size, also in optical crystals as is the case of the ZnSe Huge.

5.3. Pulse shape analysis and alpha particle discrimination

As discussed in Sections 4.1 and 4.2 the time response of the bolometers (both the LD and the scintillator crystal), is extremely slow. The light pulse has rise time of the order of few ms that – compared with the typical response of a photomultiplier or a photodiode – is extremely slow. However, at low temperature, also the light emission from scintillators is characterized by long time constants, with different values for alphas or beta/gamma's [40]. This happens also in ZnSe (as evident from Fig. 6) and a discrimination based on pulse shape analysis is achievable.

Fig. 9 shows the decay constant (left panel), of events recorded with the LD, versus the energy of the corresponding heat pulse (i.e. Heat). This plot refers to the measurement done with the ZnSe Huge crystal, exposed to a $^{232}$Th gamma source and the B alpha source, whose scatter plot is shown in Fig. 5. The three populations identified in Fig. 5 appear to have a clearly different light pulse shape:

- Events of direct ionization on the LD (circles) are very fast, with a decay time of about 5 ms. These events are interaction that involved both the LD and the scintillator. Therefore they are in coincidence with a heat pulse in the scintillator, while the energy recorded by the LD is in part due to direct ionization and in part to scintillation light. Also $^{55}$Fe events have this same decay time (they are not visible in Fig. 9 because they are not in coincidence with a heat pulse).

- Alpha events (colored spots) have an average decay time of less than 10 ms and have a distribution quite different from that of beta/gamma events (black spots). Events belonging to the $^{210}$Po line appear to have a wider distribution of the decay time than events produced by source B alphas. This looks as the same effect that, on the scatter plot of Fig. 7, makes $^{210}$Po events extend on a wide range of light amplitudes.

- Beta/gamma events (black spots) have an average decay time of less than 13 ms with a wide distribution that is partially superimposed to the alpha one.

A similar behaviour is observed on the rise time. Also the shape of heat pulses appears to be different for alpha and beta/gamma events. In the right panel of Fig. 9 it is shown the rise time of heat pulses. Beta/gammas (black spots) have a faster rise time than alphas (colored spots), the same is true for the decay time.

The reason for having a faster light response and a slower heat one in the case of alphas is not clear and will require dedicated measurements and the construction of a model for signal formation. This will probably also help in the understanding of the other anomalies of this scintillator, discussed so far.

The observed difference in pulse shapes, open in any case an important possibility for the use of ZnSe bolometers for $\beta\beta$(0$\nu$) search: the rejection of alpha particle background on the basis of the pulse shape. Indeed, while the use of the Heat to Light ratio seems to provide only a partial discrimination (due to the low Light events discussed in Section 5.2.3), the use of the pulse shape of light pulses appears much more efficient.

In a dedicated run – with optimized measuring conditions – we were able to reach a quite high alpha rejection efficiency. The ZnSe Large crystal (the one with the best LY) was mounted with – on its bottom – source B and a Sm source $^{147}$Sm alpha decays with the emission of a 2.2 MeV alpha particle). The LD was operated at a slightly higher temperature than usual, in order to have a faster re-

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**Fig. 7.** Scatter plot of Light vs. Heat recorded with the Huge ZnSe crystal in two different runs. In run I (colored points) the B alpha source was mounted on the bottom side of the crystal, opposite to the LD (this is the same scatter plot of Fig. 5). In run II (black points) source B was moved on the side of the crystal and in its place was mounted source A. The $Q_F$ obtained for the two positions of source B differ by about 20%. The dotted lines identify the opening of the alpha band on a wide angle, due to the variation of the $Q_F$ upon source position.

**Fig. 8.** Scatter plot of Light vs. Heat recorded with the Large ZnSe crystal. The detector was here exposed to the A alpha source and to the calibration gamma source ($^{232}$Th located outside the refrigerator). Each alpha peak comes with a – low light high heat – tail that draws a negative slope line in the scatter plot. In the inset: histogram of the events belonging to the 5.7 MeV alpha line (colored spots) projected along their negative slope line. The two histograms have been obtained for the same source (source A) and the same detector. The only difference being that in the case of the black histogram the non optical basis of the ZnSe cylinder was in front of the source, while in the case of the colored histogram it was the optical basis that faced the source (the scatter plot refers to this latter configuration).
response. The signal sampling was increased to 16384 points on a 4 s window, to improve the resolution on the signal shape. The result is illustrated in Fig. 10. The scatter plot (left panel) of Light vs. Heat shows clearly the alpha and beta bands. The alpha band has a quite important tail towards low Light signals and – based on the Heat/Light ratio – the alpha discrimination looks quite poor. The LD clearly distinguishes alphas from betas on the basis of their pulse shape (central panel), here measured with the TVR parameter. The projection of the TVR distribution (right panel) shows how efficient this can be this kind of discrimination; for a better visualisation of this efficiency all the signals with TVR lower than 2 appear in the scatter plot (left panel) in color. The alpha rejection efficiency was evaluated in the region 2400–2600 keV (the nearest region to the $^{82}$Se $\beta\beta$ Q-value and – in our measurement – populated enough by both beta/gamma’s and alpha’s) to be about 15 sigma (Fig. 10 right panel). Finally, the possibility of an alpha/beta discrimination based on the scintillating bolometer only (as that presented in the right panel of Fig. 9) is extraordinarily interesting since implies an oversimplification for the detector (the LD is no more necessary).

However, in our measurements, it is still not enough sensitive and reproducible. We recall here that ZnSe is not the only scintillating crystal were we have observed this characteristics; a very promising crystal is for example CaMoO$_4$ [41].

6. $\beta\beta$(0v) perspectives with ZnSe

In this section we briefly discuss the perspectives in the application of ZnSe scintillating bolometers for $\beta\beta$(0v) study. To do this we assume a FWHM energy resolution of 10 keV on the Heat signal at the Se Q-value (~2995 keV) and a ROI two FWHM wide (i.e. from 2985 to 3005 keV). For the alpha rejection we assume to use the pulse shape analysis on the light pulse, with the same efficiency reported in Section 5.3 (15 sigma).

In order to translate the results discussed here in the actual sensitivity of a $\beta\beta$ experiment based on this technique, we can refer to the only existing cryogenic setup, the one installed at LNGS (Hall A) in the 80’s by the Milano group and later used also for the CUORICINO experiment. The background model for this setup is in fact
well known [42] and the extrapolation to the technique described here can be obtained by simply substituting TeO$_2$ crystals with ZnSe ones.

For the background rate induced by environmental neutrons and muons we use the results reported in [42] and [43]. Indeed the change in the molecular compound does not affect in a relevant way the background rates. External neutrons yield a contribution integrated in the 3–4 MeV region lower than $10^{-5}$ c/keV/kg/y [42], while external muons – operating the array in anticoincidence – yield a contribution of about $8 \cdot 10^{-5}$ c/keV/kg/y in the 2–4 MeV region [43].

For the background induced by environmental gammas, the results reported in [42] do not consider the energy region above the 2615 keV line of $^{208}$Tl where the counting rate is drastically reduced as evident in Fig. 1 of [42]). In our ROI the dominant contribution comes from $^{214}$Bi and $^{208}$Tl. Indeed $^{214}$Bi has few low intensity gamma rays in or above our ROI (the total branching ratio of these gamma lines is 0.08%) while $^{208}$Tl has no gamma with energy larger than 2615 keV, but can contribute to the counting rate in our ROI through the radioactive emission of two photons with a sum energy of 3.2 MeV (the 2615 keV and 583 keV gammas). The background model developed for the Hall A set-up at LNGS, and described in [42], identifies the major source of $^{214}$Bi and $^{208}$Tl activity as due to contaminations localized in between the external and the internal lead shields. This allows us to evaluate $^{214}$Bi and $^{208}$Tl contributions in the ROI. These are: $\sim 0.006$ c/keV/kg/y from $^{214}$Bi (dominated by the 3000 keV line) and $3 \cdot 10^{-5}$ c/keV/kg/y from $^{208}$Tl.

Concerning the background contribution of the detector itself, the 15 sigma efficiency in alpha rejection reduce – for reasonable contamination levels of the surfaces and of the crystal bulk – to absolutely negligible values the alpha rate in the ROI. Finally, the use of delayed coincidences allows to get rid of the most worrisome background arising from $^{238}$U and $^{232}$Th crystal bulk contaminations. The measured upper limits on the ZnSe (the Huge crystal) internal contaminations are of 0.4 $\mu$Bq/kg (at 90% CL) for both the two chains; these contaminations results in a counting rate of about $6 \cdot 10^{-4}$ c/keV/kg/y in the ROI, dominated by the radioactive contamination of the detector is lower than $10^{-4}$ c/keV/kg/y, proving that – in an extremely low background set-up – very high sensitivities for the $\beta\beta(0\nu)$ process are achievable.

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References